



MCH3222

 — NPN Epitaxial Planar Silicon Transistor

DC / DC Converter Applications

Applications

- Relay drivers, lamp drivers, motor drivers, flash.

Features

- Adoption of FBET, MBIT processes.
- Large current capacitance.
- Low collector-to-emitter saturation voltage.
- High-speed switching.
- Narrow h_{FE} range.
- Ultrasmall package facilitates miniaturization in end products (mounting height : 0.85mm).
- High allowable power dissipation.

Specifications

Absolute Maximum Ratings at $T_a=25^\circ\text{C}$

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	V_{CB0}		100	V
Collector-to-Emitter Voltage	V_{CES}		100	V
	V_{CEO}		50	V
Emitter-to-Base Voltage	V_{EBO}		6	V
Collector Current	I_C		3	A
Collector Current (Pulse)	I_{CP}	$PW \leq 1\text{ms}$	6	A
Base Current	I_B		600	mA
Collector Dissipation	P_C	Mounted on a ceramic board (600mm ² X0.8mm)	0.8	W
Junction Temperature	T_J		150	$^\circ\text{C}$
Storage Temperature	T_{stg}		-55 to +150	$^\circ\text{C}$

Electrical Characteristics at $T_a=25^\circ\text{C}$

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Collector Cutoff Current	I_{CB0}	$V_{CB}=40\text{V}, I_E=0\text{A}$			0.1	μA
Emitter Cutoff Current	I_{EBO}	$V_{EB}=4\text{V}, I_C=0\text{A}$			0.1	μA
DC Current Gain	h_{FE}	$V_{CE}=2\text{V}, I_C=100\text{mA}$	250		400	
Gain-Bandwidth Product	f_T	$V_{CE}=10\text{V}, I_C=500\text{mA}$		380		MHz

Marking : CV

Continued on next page.

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MCH3222

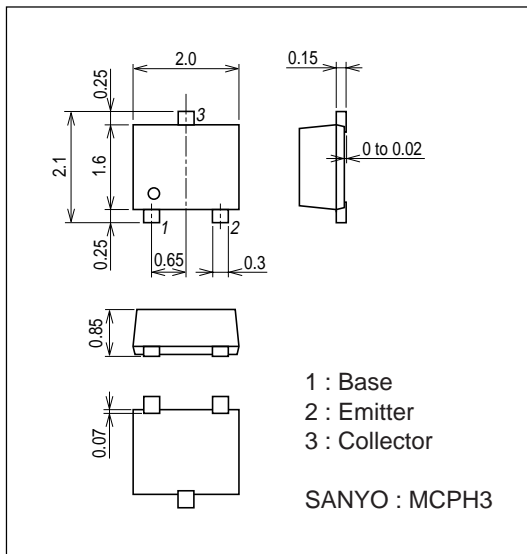
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Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Output Capacitance	Cob	$V_{CB}=10V, f=1MHz$		13		pF
Collector-to-Emitter Saturation Voltage	$V_{CE(sat)1}$	$I_C=1A, I_B=50mA$		60	90	mV
	$V_{CE(sat)2}$	$I_C=2A, I_B=100mA$		100	150	mV
Base-to-Emitter Saturation Voltage	$V_{BE(sat)}$	$I_C=2A, I_B=100mA$		0.88	1.2	V
Collector-to-Base Breakdown Voltage	$V_{(BR)CBO}$	$I_C=10\mu A, I_E=0A$	100			V
Collector-to-Emitter Breakdown Voltage	$V_{(BR)CES}$	$I_C=100\mu A, R_{BE}=0\Omega$	100			V
	$V_{(BR)CEO}$	$I_C=1mA, R_{BE}=\infty$	50			V
Emitter-to-Base Breakdown Voltage	$V_{(BR)EBO}$	$I_E=10\mu A, I_C=0A$	6			V
Turn-ON Time	t_{on}	See specified Test Circuit.		35		ns
Storage Time	t_{stg}	See specified Test Circuit.		300		ns
Fall Time	t_f	See specified Test Circuit.		22		ns

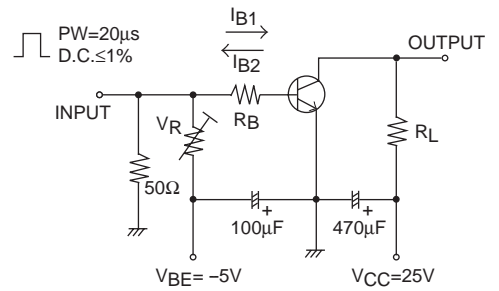
Package Dimensions

unit : mm

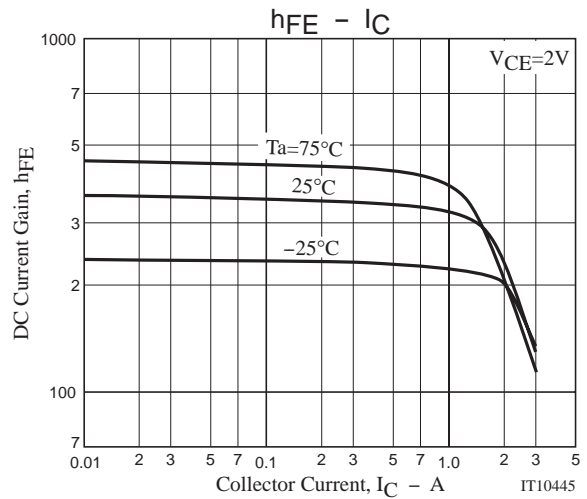
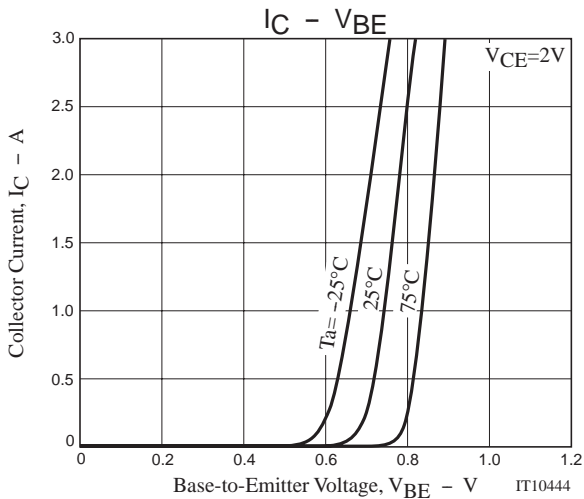
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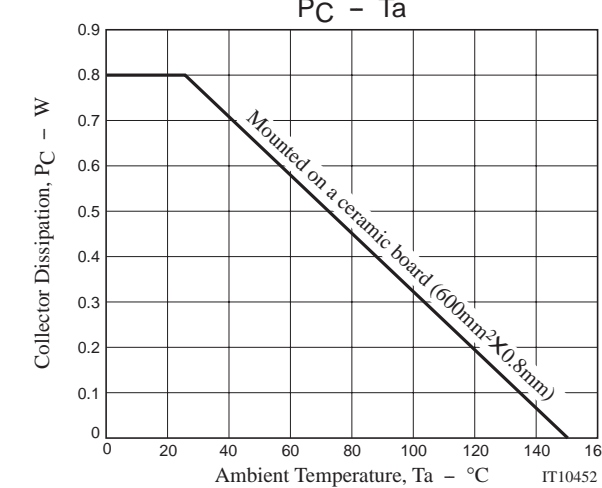
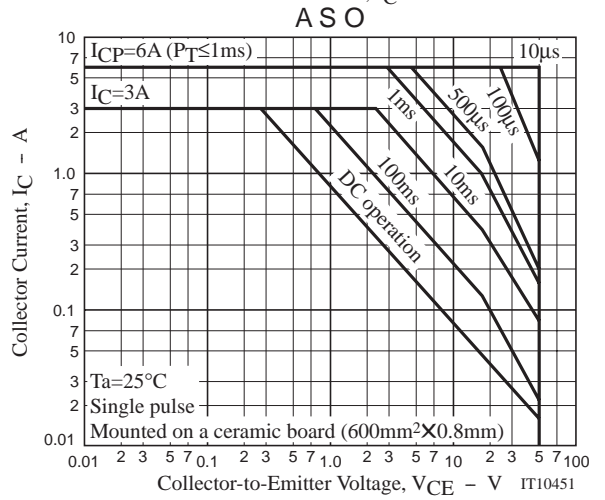
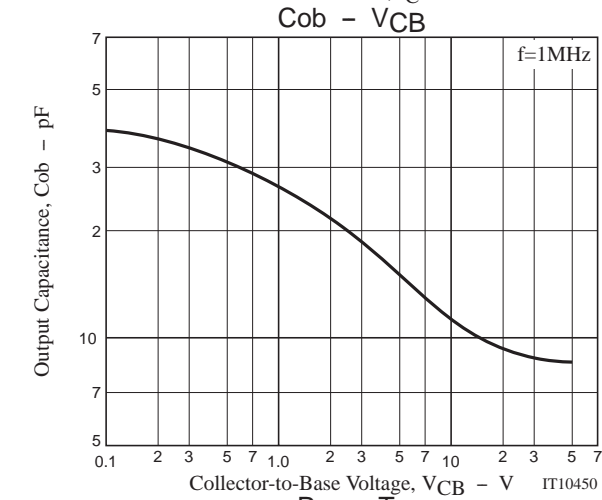
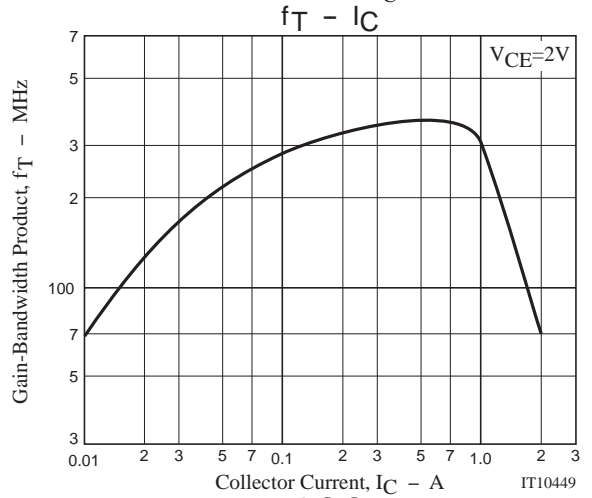
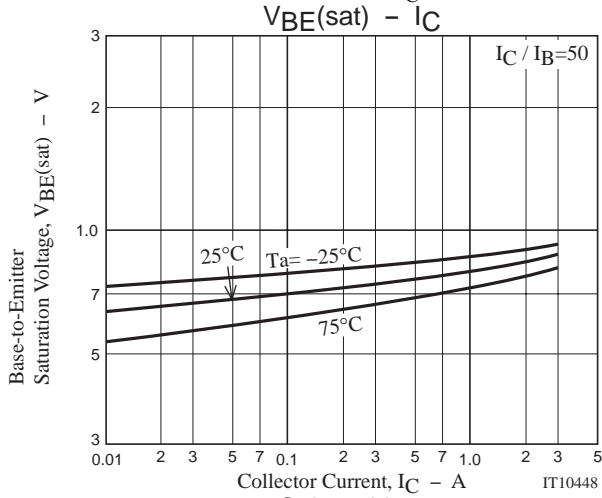
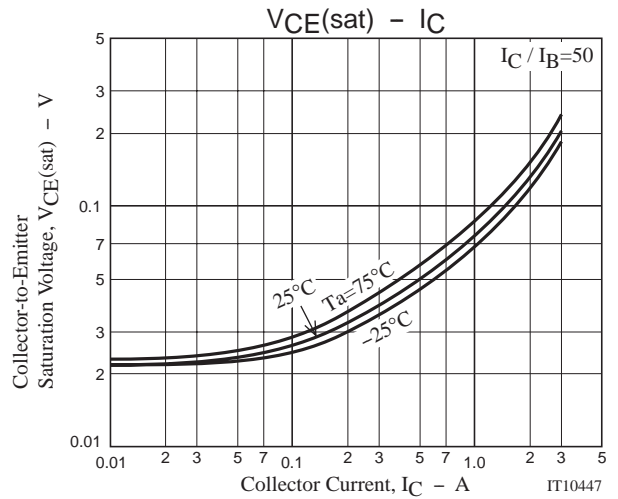
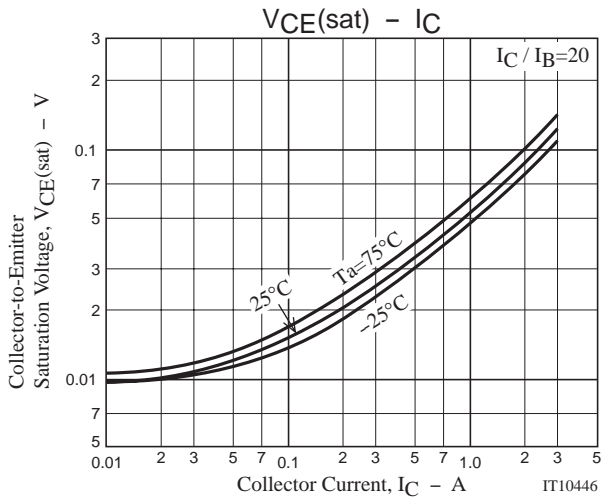
Switching Time Test Circuit



$$I_C = 10I_{B1} = -10I_{B2} = 1A$$



MCH3222



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